

SEMITOP® 2

# Antiparallel Thyristor Module

#### **SK 45 WT**

**Preliminary Data** 

#### **Features**

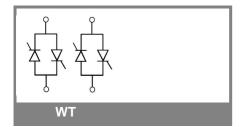
- Compact Design
- · One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passived thyristor chips
- Up to 1600V reverse voltage
- UL recognized, file no. E 63 532

### **Typical Applications**

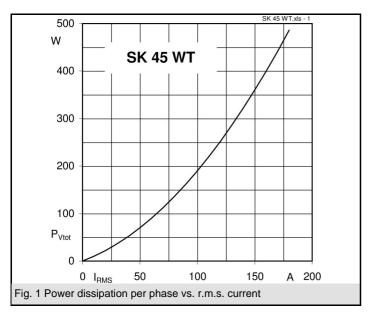
- Soft starters
- Light control (studios, theaters...)
- Temperature control

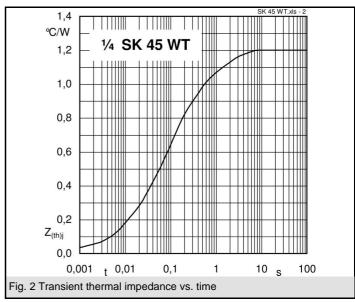
V <sub>RSM</sub> V	V <sub>RRM</sub> , V <sub>DRM</sub> V	I <sub>RMS</sub> = 47 A A (full conduction) (T <sub>s</sub> = 85 °C)
900	800	SK 45 WT 08
1300	1200	SK 45 WT 12
1700	1600	SK 45 WT 16

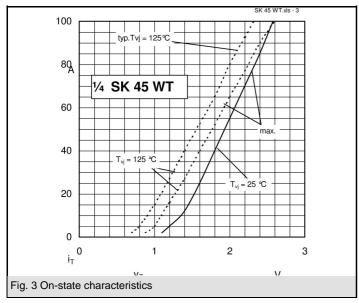
Symbol	Conditions	Values	Units
I <sub>RMS</sub>	W1C ; sin. 180° ; T <sub>s</sub> = 100°C	33	Α
	W1C ; sin. 180° ; T <sub>s</sub> = 85°C	47	Α
I <sub>TSM</sub>	T <sub>vi</sub> = 25 °C ; 10 ms	450	Α
	T <sub>vi</sub> = 125 °C ; 10 ms	380	Α
i²t	T <sub>vj</sub> = 25 °C ; 8,310 ms	1000	A²s
	T <sub>vj</sub> = 125 °C ; 8,310 ms	720	A²s
V <sub>T</sub>	T <sub>vj</sub> = 25 °C, I <sub>T</sub> = 75 A	max. 1,9	V
$V_{T(TO)}$	T <sub>vi</sub> = 125 °C	max. 1	V
r <sub>T</sub>	T <sub>vi</sub> = 125 °C	max. 10	mΩ
$I_{DD};I_{RD}$	$T_{vj} = 25 ^{\circ}\text{C},  V_{RD} = V_{RRM}$	max. 0,5	mA
	$T_{vj}$ = 125 °C, $V_{RD} = V_{RRM}$	max. 10	mA
t <sub>gd</sub>	$T_{vj}$ = 25 °C, $I_{G}$ = 1 A; $di_{G}/dt$ = 1 A/ $\mu$ s	1	μs
$t_{gr}$	V <sub>D</sub> = 0,67 *V <sub>DRM</sub>	2	μs
(dv/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	1000	V/µs
(di/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C; f= 5060 Hz	50	A/µs
t <sub>q</sub>	$T_{vi}^{yj}$ = 125 °C; typ.	120	μs
I <sub>H</sub>	T <sub>vi</sub> = 25 °C; typ. / max.	80 / 150	mA
$I_{L}$	$T_{vj}^{'}$ = 25 °C; $R_G$ = 33 $\Omega$ ; typ. / max.	150 / 300	mA
V <sub>GT</sub>	$T_{vi} = 25 ^{\circ}\text{C}; \text{d.c.}$	min. 3	V
I <sub>GT</sub>	$T_{vi}^{s}$ = 25 °C; d.c.	min. 100	mA
$V_{GD}$	$T_{vi}^{s}$ = 125 °C; d.c.	max. 0,25	V
$I_{GD}$	T <sub>vj</sub> = 125 °C; d.c.	max. 3	mA
$R_{th(j-s)}$	cont. per thyristor	1,2	K/W
	sin 180° per thyristor	1,24	K/W
$R_{th(j-s)}$	cont. per W1C	0,6	K/W
. 0 -7	sin 180° per W1C	0,62	K/W
$T_{vi}$		-40 <b>+</b> 125	°C
T <sub>stg</sub>		-40 <b>+</b> 125	°C
T <sub>solder</sub>	terminals, 10s	260	°C
V <sub>isol</sub>	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3000 / 2500	V~
$M_s$	Mounting torque to heatsink	1,5	Nm
$M_t$			Nm
а			m/s²
m		13	g
Case	SEMITOP® 2	T 37	

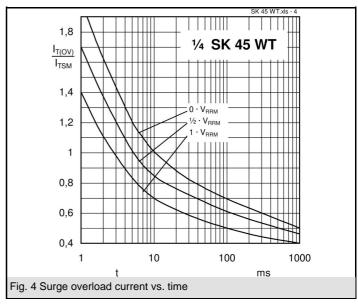


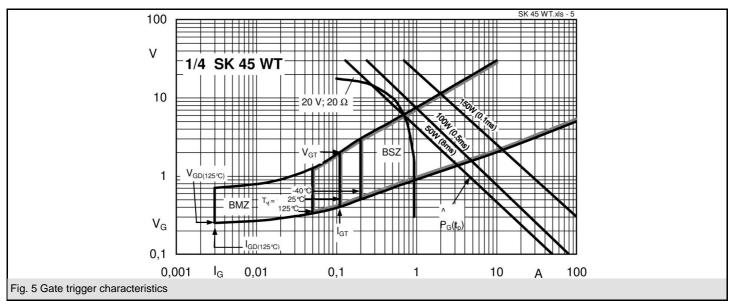
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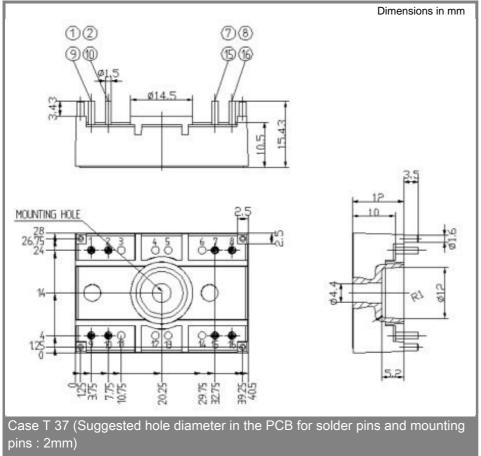


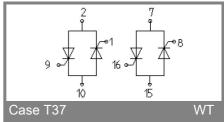












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